

RK8xx Series 8A TRIACS

DESCRIPTION:

High current density due to double mesa technology, glass passivation.

RK8xx series triacs are suitable for general purpose AC switching, They can be used as an ON/OFF function in applications such as static relays, heating regulation, induction motor stating circuits...or for phase contol operation, light dimmers, motor speed controllers.

RK8xx are 3 quadrants triacs, They are specially recommerded for use on inductive loads.

MAIN FEATURES

Symbol	Value	Unit
IT(RMS)	8	Α
VDRM/VRRM	600 and 800	V
Vтм	1.55	V

TO-251(iPAK) TO-252(DPAK) T1 (1) G (3) T2 (2)

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit		
Storage junction temperature range	Tstg	-40 to +150	°C		
Operrating junction temperature range		Tj	-40 to +125	°C	
Repetitive Peak Off-state Voltage	Tj=25°C	VDRM	600 and 800	.,	
Repetitive Peak Reverse Voltage	Tj=25°C	VRRM	600 and 800	V	
Non repetitive Surge Peak Off-state Voltage	t=-10== Ti-25°C	Vdsm	700 and 900	.,	
Non repetitive Peak Reverse Voltage	tp=10ms,Tj=25°C	Vrsm	700 and 900	V	
PMS on state current (full sine ways)	RK8xxHTc=110°C	IT(RMS)	0	A	
RMS on-state current (full sine wave)	RK8xxKTc=110°C	TI(KIVIS)	8		
Non repetitive surge peak on-state current	f = 60 Hz t=16.7ms	Ітем	84	_	
(full cycle,Tj=25°C)	f = 50 Hz t=20ms	ITSM	80	Α	
I²t Value for fusing	tp=10ms	l²t	36	A²s	
Critical rate of rise of on-state current (IG=2×IGT,tr≤100 ns,f=120Hz,Tj=125°C)	dl /dt	50	A/µs		
Peak gate current (tp=20us,Tj=125°C)	lgм	4	Α		
Peak Gate Power Dissipation (tp=20us,Tj=12	Рдм	10	W		
Average gate power dissipation (Tj=125°C)		PG(AV)	1	W	

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ELECTRICAL CHARACTERISTICS (Tj=25°C unless otherwise specified)

3 Quadrants

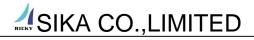
Symbol	Test Condition	Quadrant		RK8xx				Unit
Cymbol	rest condition	Quadrant		805	810	835	850	Offic
lgт	VD=12V RL=33Ω	1-11-111	MAX.	5	10	35	50	mA
VGT	VD-12V KL-3322	1-11-111	MAX.	1.3			V	
VGD	VD=VDRM RL=3.3KΩ Tj =125℃	1-11-111	MIN.	0.2				V
1.			MAX.	15	20	50	70	mA
IL	IG=1.2IGT	II	MAX.	25	35	60	80	mA
Iн	IT =100mA			10	15	40	60	mA
dV/dt	VD=67%VDRM gate open Tj=125℃			20	40	400	1000	V/µs
(dV/dt)c	(dl/dt)c=3.5A/ms Tj=125℃	MIN.	0.5	1	10	25	V/µs	

STATIC CHARACTERISTICS

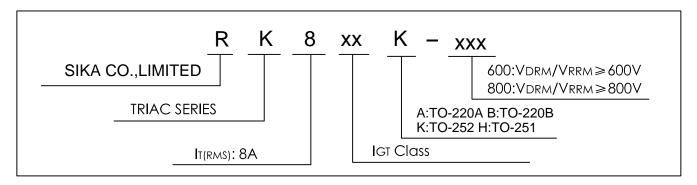
Symbol	Parame	Value(MAX.)	Unit	
VTM	Iτм=11A,tp=380μs		1.55	V
IDRM	VD=VDRM VR=VRRM	Tj=25℃	5	μΑ
IRRM		Tj=125℃	1	mA

THERMAL RESISTANCES

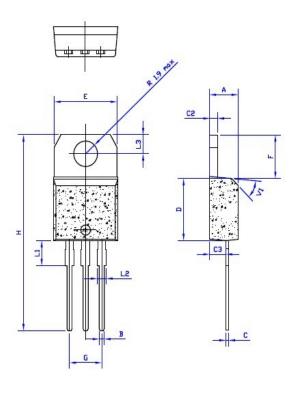
Symbol	Pá	Value	Unit		
Rth(J -C)	Junction to Case(AC)		RK8xxH/RK8xxK	1.6	°C/W
Rth(j-a)	Junction to ambient	S=0.5cm²	RK8xxK	70	°C/W
TXIIIy-a)	Junction to ambient		RK8xxH	100	C/VV



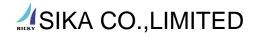
ORDERING INFORMATION



TO-220A insulated package and TO-220B non-insulated package

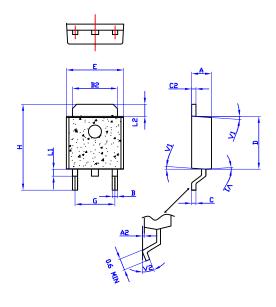


	Dimensions						
Ref.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	4.4		4.6	0.173		1.181	
В	0.61		0.88	0.024		0.034	
С	0.46		0.70	0.018		0.027	
C2	1,23		1,32	0,048		0.051	
С3	2.4		2.72	0.094		0.107	
D	8.6		9.7	0.338		0.382	
Е	9.8		10.4	0.386		0.409	
F	6.2		6.6	0.244		0.259	
G	4.8		5.4	0.189		0.213	
Н	28.0		29.8	11.0		11.7	
L1		3.75	60		0.147		
L2	1.14		1.7	0.044	·	0.066	
L3	2.65		2.95	0.104		0.116	
V1		40°) (S.	40°	8	



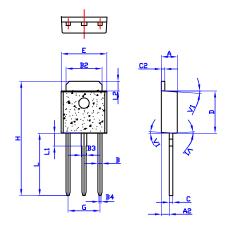
PACKAGE MECHANICAL DATA

TO-252(DPAK)



	Dimensions							
Ref.	Millimeters			Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α	2.2		2.4	0.086		0.095		
A2	0.03		0.23	0.001		0.009		
В	0.55		0.65	0.021		0.026		
B2	5.1		5.4	0.200		0.212		
С	0.45		0.62	0.017		0.024		
C2	0.48		0.62	0.019		0.024		
D	6		6.2	0.236		0.244		
Е	6.4		6.7	0.252		0.264		
G	4.40		4.70	0.173		0.185		
Н	9.35		10.1	0.368		0.397		
L1		8.0			0.031			
L2	1.37		1.5	0.054		0.059		
V1		4°			4°			
V2	0°		8°	0°		8°		

TO-251(iPAK)



	Dimensions						
Ref.	Mi	llimete	ers	Inches			
	Min.	Тур.	Max.	Min	Тур.	Max.	
Α	2.2		2.4	0.086		0.095	
A2	0.9		1.1	0.035		0.043	
В	0.55		0.65	0.021		0.026	
B2	5.1		5.4	0.200		0.212	
В3	0.76		0.85	0.030		0.033	
B4		0.32			0.013		
С	0.45		0.62	0.017		0.024	
C2	0.48		0.62	0.019		0.024	
D	6		6.2	0.236		0.244	
E	6.4		6.7	0.252		0.264	
G	4.4		4.7	0.173		0.185	
Н	16.0		16.7	0.630		0.658	
L	8.9		9.4	0.350		0.370	
L1	1.8		1.9	0.071		0.075	
L2	1.37		1.5	0.054		0.059	
V1		4°			4°		



FIG.1:Maximum power dissipation versus RMS on-state current(full cycle)

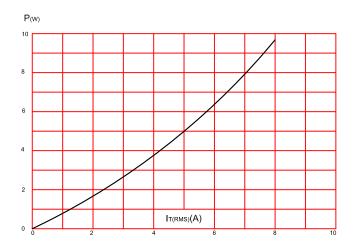


FIG.2:RMS on-state current versus case temperature(full cycle)

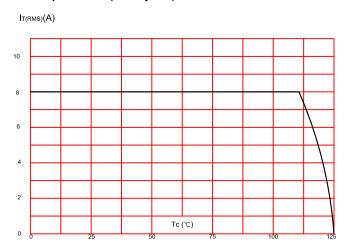


FIG.3:On-state characteristics (maximum values).

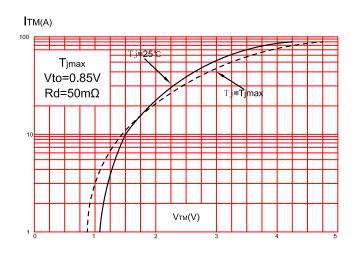


FIG.4:Surge peak on-state current versus number of cycles.

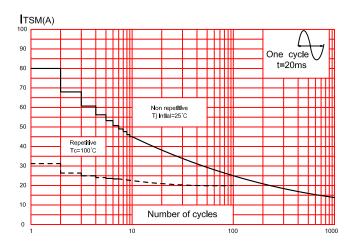


FIG.5:Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<10ms,and corresponding value of l²t.

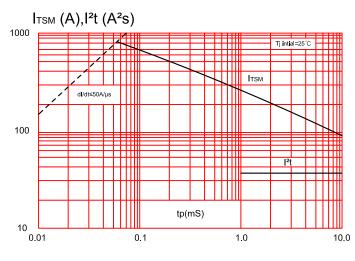
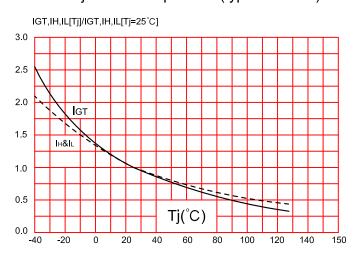


FIG.6:Relative variations of gate trigger current, holding current and latching current versus junction temperature(typical values)



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